


Substitute Form PTO-1449 (Modified)	U.S. Department of Commerce Patent and Trademark Office	Attorney's Docket No. 07977-218003	Application No. New Divisional Appln.
Information Disclosure Statement by Applicant (Use several sheets if necessary) (37 CFR §1.98(b))		Applicant Shunpei Yamazaki et al.	
		Filing Date January 9, 2004	Group Art Unit Unknown



U.S. Patent Documents							
Examiner Initial	Desig. ID	Document Number	Publication Date	Patentee	Class	Subclass	Filing Date If Appropriate
	AA	5,170,244	12/08/92	Dohjo, et al.			
	AB	5,250,931	10/05/93	Misawa, et al.			
	AC	5,525,822	06/11/96	Vinal			
	AD	5,744,824	04/28/98	Kousai, et al.			
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	AN	6,147,667	11/14/00	Yamazaki, et al.			
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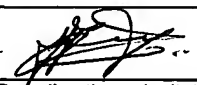
Foreign Patent Documents or Published Foreign Patent Applications								
Examiner Initial	Desig. ID	Document Number	Publication Date	Country or Patent Office	Class	Subclass	Translation	
							Yes	No
	AS	1118521	03/13/96	China			ABS	
	AT	JP 07-135318	05/23/95	Japan			ABS	
	AU	JP 08-078329	03/22/96	Japan			ABS	
	AV	JP 08 213634	08/20/96	Japan			ABS	
	AW	JP 08 288522	11/01/96	Japan			ABS	
	AX	JP 09-022077	01/20/97	Japan			Full	

Examiner Signature J. MONDT	Date Considered 03/25/05
EXAMINER: Initials citation considered. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.	

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Foreign Patent Documents or Published Foreign Patent Applications								
Examiner Initial	Desig. ID	Document Number	Publication Date	Country or Patent Office	Class	Subclass	Translation	
							Yes	No
	AY	JP 09-312260	12/02/97	Japan			ABS	
	AZ	JP 10-270363	10/09/98	Japan			ABS	

Other Documents (include Author, Title, Date, and Place of Publication)		
Examiner Initial	Desig. ID	Document
	BA	Kuznetsov, et al., "Silicide precipitate formation and solid phase regrowth of Ni+-implanted amorphous silicon", Inst. Phys. Conf. Ser. No. 134:Section 4, Paper presented at Microsc. Semicond. Mater. Conf., April 1993, pp. 191-194.
	BB	Kuznetsov, et al., "Transient kinetics in solid phase epitaxy of Ni doped amorphous silicon", Nuclear Instruments & Methods in Physics Research, B 96, 1995, pp. 261-264.
	BC	
	BD	

Examiner Signature <i>J. MONDT</i> 	Date Considered 03/25/05
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